Diode Semiconductor Device - Page 1 of 1

AeroBase Group

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Inclosure N	Aaterial:
Glass	
Overall Ler	ngth:
0.256 inche	S
Terminal L	ength:
Between 0.8	880 inches and 1.000 inches
Overall Dia	imeter:
0.336 inche	S
Mounting M	Method:
Terminal	
Features P	rovided:
Hermetically	y sealed case
Semicondu	uctor Material:
Silicon	
Voltage Ra	ting In Volts Per Characteristic:
100.0 reve	rse voltage, peak
Current Ra	ting Per Characteristic:
1.50 amper	es forward current, average absolute
Maximum (	Operating Tempurature Per Measurement Point:
175.0 degre	ees celsius ambient air
Terminal T	ype And Quantity:
2 uninsulate	ed wire lead
Specificati	on Data:
80131-relea	ase3616 professional/industrial association specification
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	